Low Phase Jitter Crystal Oscillator: SG3225 / 5032 / 7050EEN

Features

Crystal oscillator (SPXO)

• Frequency range (fo): 25 MHz to 500 MHz

Output: LVPECL

Supply voltage: 2.5 V Typ. / 3.3 V Typ.
 Operating temperature: -40 °C to +105 °C

● Low phase jitter: 50 fs Typ. (fo = 156.25 MHz)

SG3225EEN SG5032EEN SG7050EEN (3.2 × 2.5 × 1.05 mm) (5.0 × 3.2 × 1.3 mm) (7.0 × 5.0 × 1.5 mm)

Applications

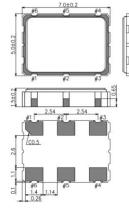
- Network equipment (Router, Switch, Optical module, etc.)
- Data center
- Test and Measurement Equipment, Factory Automation
- High Speed Converters like ADC and DAC

Description

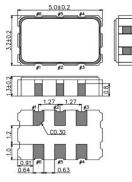
5G will increase the communication traffic exponentially. A 5G communication network requires high-speed and wide-band, while keeping the noise level to a minimum. This can be achieved with a high frequency low jitter reference clock for the communication equipment. Using the above XO, customers can input a high frequency reference (up to 500 MHz) with extremely low phase jitter and power, from a fundamental mode crystal to achieve excellent phase noise.

Outline Drawing and Terminal Assignment

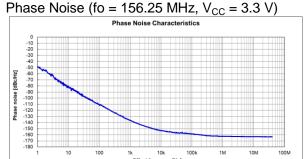




SG5032EEN



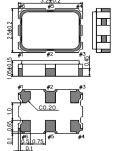
Typical Performance



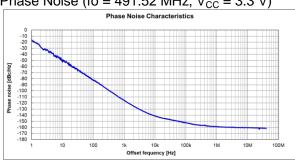
Phase Jitter (12 kHz to 20 MHz): 50 fs Typ.

Pin	Connection
1	OE
2	N.C. (Open or V _{CC})
3	GND
4	OUT
5	OUT
6	Vcc

SG3225EEN



Phase Noise (fo = 491.52 MHz, V_{CC} = 3.3 V)



Phase Jitter (12 kHz to 20 MHz): 20 fs Typ.

[1] Product Number / Product Name

(1-1) Product Number

SG3225EEN: X1G005221xxxx00 (fo ≤ 200 MHz)

X1G005511xxxx00 (fo > 200 MHz)

SG5032EEN: X1G005531xxxx00 (fo > 200 MHz) SG7050EEN: X1G005131xxxx00 (fo ≤ 200 MHz)

X1G005551xxxx00 (fo > 200 MHz) (Please contact Epson for details)

(1-2) Product Name (Standard Form)

1)Model

2Output (E: LVPECL)

3Frequency

4 Supply voltage

⑤Frequency tolerance

©Operating temperature

7 Internal identification code

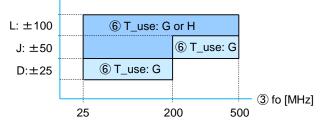
("A" is default)

 4Sι	ipply voltage
	2.5 V Typ.
С	3.3 V Typ.

5 Frequency tolerance									
D	$\pm 25 \times 10^{-6}$								
J	±50 × 10 ⁻⁶								
L	$+100 \times 10^{-6}$								

6Operating temperature						
G	-40 °C to +85 °C					
	-40 °C to +105 °C					

Available code for **©**Operating temperature **⑤** f_tol [x 10⁻⁶]



Please note that the available code for ⑥Operating temperature (T_use) depends on ③Frequency (fo) and ⑤Frequency tolerance (f_tol).

[2] Absolute Maximum Ratings

Parameter	Symbol	Specification			Unit	Conditions	
raiameter	Symbol	Min.	Тур.	Max.	Offic	Conditions	
Maximum aupply valtage	V _{CC}	-0.5	-	4	V	fo ≤ 200 MHz	
Maximum supply voltage		-0.5	-	5	V	fo > 200 MHz	
Input voltage	Vin	-0.5	-	$V_{CC} + 0.5$	V	OE terminal	
Storage temperature range	T_stg	-55	-	125	°C		

[3] Operating Range

Parameter	Symbol		Specification	า	Unit	Conditions	
	Symbol	Min.	Тур.	Max.			
Supply voltage	V _{CC}	2.375	2.5	2.625	V	Suffix: D	
Supply voltage	V CC	3.135	3.3	3.465	V	Suffix: C	
Supply voltage	GND	0.0	0.0	0.0	V		
Operating temperature range	T_use	-40	+25	+85	°C	Suffix: G	
Operating temperature range		-40	+25	+105	٥C	Suffix: H	
ECL load condition L_ECL		50			Ω	Terminated to V _{CC} - 2.0 V	

^{*} Power supply startup time (0 %V_{CC} \rightarrow 90 %V_{CC}) should be more than 150 μs

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 $^{^{\}star}$ A 0.1 μF and a 10 μF bypass capacitor should be connected between V_{CC} and GND pins located close to the device

[4] Frequency Characteristics

(Unless stated otherwise [3] Operating Range)

4 ji requericy Characteristics	(Offices stated otherwise [3] Operating realized					
Parameter	Symbol	Specification			Unit	Conditions
Farameter	Symbol	Min.	Тур.	Max.	Offic	Conditions
Output frequency *1	fo	25	-	500	MHz	SG3225EEN / SG7050EEN
Output frequency 1	10	200	-	500	MHz	SG5032EEN
	f_tol	-25	-	+25	×10 ⁻⁶	*2 Suffix: D fo ≤ 200 MHz, T_use: G
Frequency tolerance		-50	1	+50	×10 ⁻⁶	*3 Suffix: J T_use: G *3 Suffix: J fo≤ 200 MHz, T_use: H
		-100	-	+100	×10 ⁻⁶	*3 Suffix: L T_use: H

^{*1} Please contact Epson for available frequencies

[5] Electrical Characteristics

(Unless stated otherwise [3] Operating Range)

5 Electrical Characteristics	1		Specification	` '	otatoa otri	T Operating Range	
Parameter	Symbol			Unit	Conditions		
		Min.	Тур.	Max.		<u> </u>	
Startup time	t_str	-	-	10	ms	t = 0 at 90 %V _{CC}	
Current consumption	I _{cc}	-	-	60	mA		
Disable current	I_dis	-	-	25	mΑ	OE = GND	
Rise time / Fall time	tr / tf	-	-	0.3	ns	$V_{CC} = 3.3 \text{ V} \pm 10 \text{ %},$ $fo \le 200 \text{ MHz},$ $20 \text{ %} - 80 \text{ %} (V_{OH} - V_{OL})$	
		-	-	0.35	ns	All other, 20 % - 80 % (V _{OH} - V _{OL})	
Symmetry	SYM	45	50	55	%	At output crossing point	
Output voltage	V_{OH}	V _{CC} - 1.1	-	-	V	DC characteristics	
Output voltage	V _{OL}	-	-	V _{CC} - 1.5	V	DC characteristics	
lanut valtage	V_{IH}	70 % V _{CC}	-	-	V	OE terminal	
Input voltage	V_{IL}	-	-	30 % V _{CC}	V	OL IGIIIIIIdi	
Output disable time (OE)	tstp_oe	-	-	100	ns	OE terminal HIGH → LOW	
Output enable time (OE)	teta oo	-	-	200	ns	fo ≤ 200 MHz, OE terminal LOW → HIGH	
Output enable time (OL)	tsta_oe	-	-	500	ns	fo > 200 MHz, OE terminal LOW → HIGH	
Phase jitter (fo = 25 MHz)	t _{PJ}	-	-	250	fs	Offset frequency 12 kHz to 5 MHz	
Phase jitter (fo = 50 MHz)	t _{PJ}	-	-	250	fs		
Phase jitter (fo = 100 MHz)	t _{PJ}	-	-	100	fs	7	
Phase jitter (fo = 125 MHz)	t _{PJ}	-	-	90	fs	Ī	
Phase jitter (fo = 156.25 MHz)	t _{PJ}	-	-	70	fs	Offset frequency 12 kHz to 20 MHz	
Phase jitter (fo = 212.5 MHz)	t _{PJ}	-	-	60	fs		
Phase jitter (fo = 312.5 MHz)	t _{PJ}	-	-	60	fs		
Phase jitter (fo = 491.52 MHz)	t _{PJ}	-	-	40	fs		

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^{*2} Frequency tolerance includes Initial frequency tolerance, Frequency / temperature characteristics, Frequency / voltage coefficient and aging (5 years, +25 °C).

^{*3} Frequency tolerance includes Initial frequency tolerance, Frequency / temperature characteristics, Frequency / voltage coefficient and aging (10 years, +25 °C).

n = 50 pcs

n = 50 pcs

[6] Thermal resistance (For reference only)

Parameter	Symbol	Specification			Unit	Conditions
Falallielei	Symbol	Min.	Тур.	Max.	Offic	Conditions
Junction temperature	Tj	-	-	140	°C	
	θјс	1	97.9	-	°C/W	SG3225EEN
Junction to case		-	102.6	-	°C/W	SG5032EEN
		-	42.6	-	°C/W	SG7050EEN
		-	155.4	-	°C/W	SG3225EEN
Junction to ambient	θја	-	150.1	-	°C/W	SG5032EEN
		-	75.2	-	°C/W	SG7050EEN

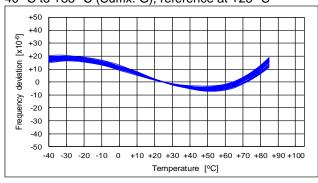
[7] Typical Performance Characteristics (For reference only)

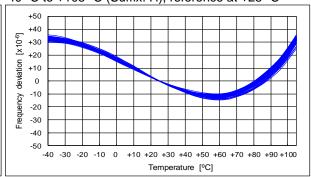
The following data shows typical performance characteristics

(7-1) Frequency / Temperature Characteristics

fo = 100 MHz-40 °C to +85 °C (Suffix: G), reference at +25 °C

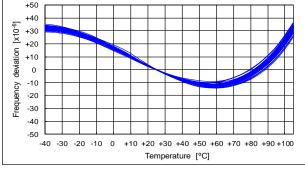
n = 50 pcs-40 °C to +105 °C (Suffix: H), reference at +25 °C





fo = 125 MHz-40 °C to +85 °C (Suffix: G), reference at +25 °C

-40 °C to +105 °C (Suffix: H), reference at +25 °C +40 +40 [x10⁻⁶] +30 +30 +20 +20 +10 +10 0 0 -10 -10 Frequency -20 -20 -30



fo = 156.25 MHz-40 °C to +85 °C (Suffix: G), reference at +25 °C

-40

-30

-40

-40 -30 -20 -10 0

-40 °C to +105 °C (Suffix: H), reference at +25 °C +50 +50 +40 +40 +30 +30 +20 +20 deviation deviation +10 +10 0 0 -10 -10 Frequency -20

+10 +20 +30 +40 +50 +60 +70 +80 +90 +100

Temperature [°C]

-40 -30 -20 -10 0 +10 +20 +30 +40 +50 +60 +70 +80 +90 +100

Temperature [°C]

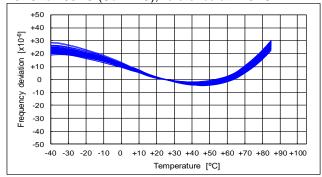
Frequency -20 -30 -40 -40 -30 -20 -10 0 +10 +20 +30 +40 +50 +60 +70 +80 +90 +100 Temperature [°C]

(7-1) Frequency / Temperature Characteristics [cont'd]

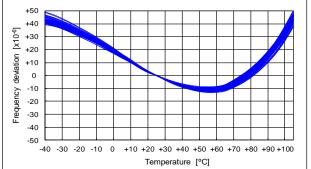
fo = 212.5 MHz

n = 50 pcs

-40 °C to +85 °C (Suffix: G), reference at +25 °C



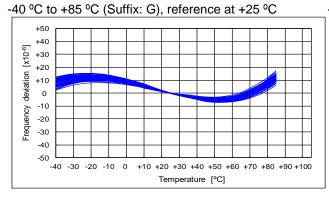
-40 °C to +105 °C (Suffix: H), reference at +25 °C

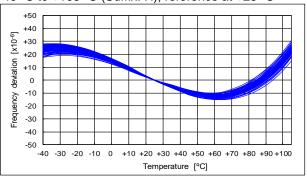


fo = 312.5 MHz

312.5 MHz

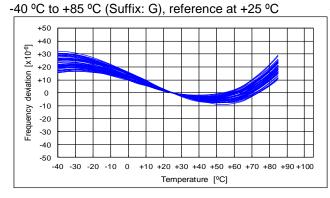
n = 50 pcs -40 °C to +105 °C (Suffix: H), reference at +25 °C

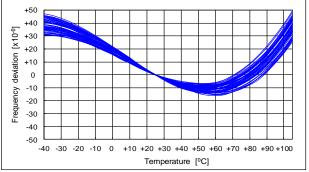




fo = 491.52 MHz

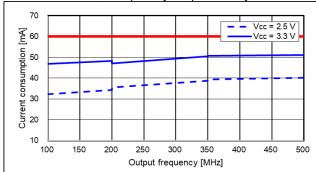
n = 50 pcs -40 °C to +105 °C (Suffix: H), reference at +25 °C

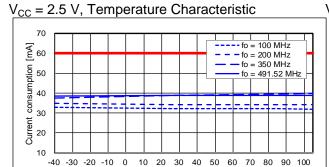




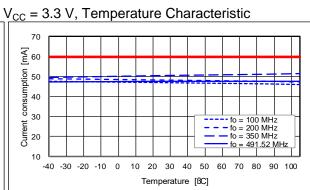
(7-2) Current Consumption

T_use = +25 °C, Frequency Dependency



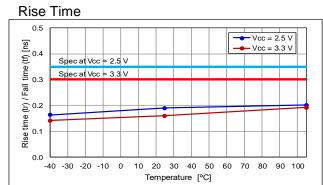


Temperature [BC]

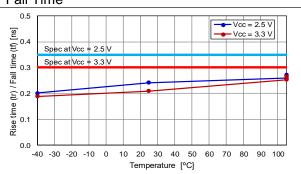


(7-3) Rise Time / Fall Time Temperature Characteristic

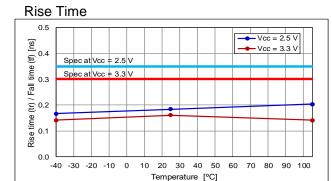
fo = 100 MHz



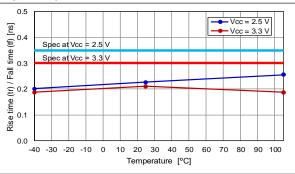
Fall Time



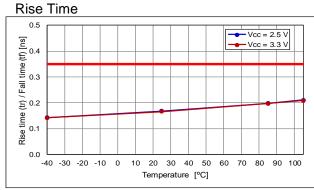
fo = 200 MHz



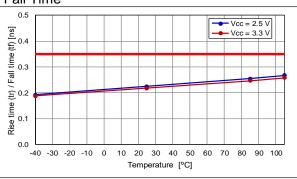
Fall Time



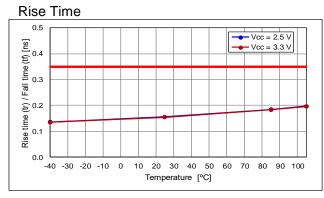
fo = 350 MHz



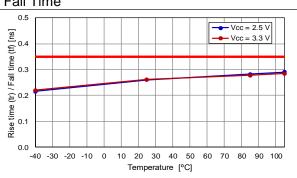
Fall Time



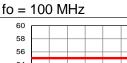
fo = 491.52 MHz

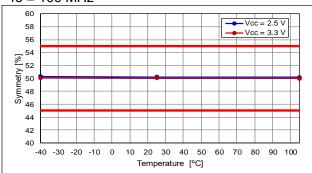


Fall Time

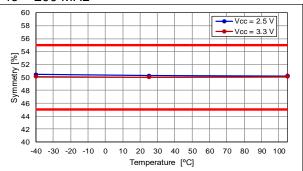


(7-4) Symmetry Temperature Characteristic

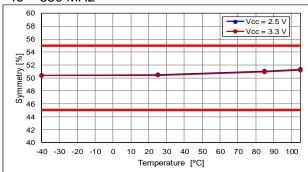




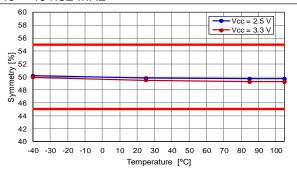




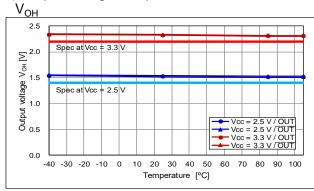


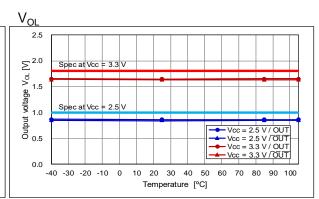


fo = 491.52 MHz



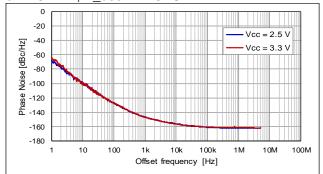
(7-5) Output Voltage Temperature Characteristic





(7-6) Phase Noise and Phase Jitter

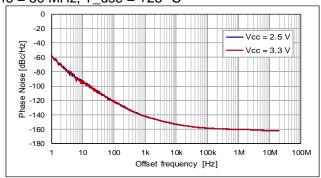
fo = 25 MHz, T_use = +25 °C



V_{CC}	Phase Jitter*
2.5 V	155 fs
3.3 V	165 fs

* Offset frequency: 12 kHz to 5 MHz

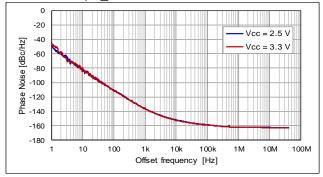
fo -	50 M	1H2 T	בפוו	= +25	\circ
10 —	. J() IV	11 12. 1	use	– TZ J	



V _{CC}	Phase Jitter*
2.5 V	161 fs
3.3 V	164 fs

* Offset frequency: 12 kHz to 20 MHz

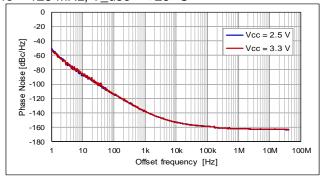
fo = 100 MHz, T_use = +25 °C



V_{CC}	Phase Jitter*
2.5 V	75 fs
3.3 V	74 fs

* Offset frequency: 12 kHz to 20 MHz

fo = 125 MHz, T_use = +25 °C

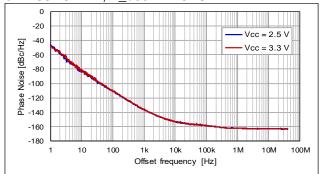


V_{CC}	Phase Jitter*
2.5 V	57 fs
3.3 V	57 fs

* Offset frequency: 12 kHz to 20 MHz

(7-6) Phase Noise and Phase Jitter [cont'd]

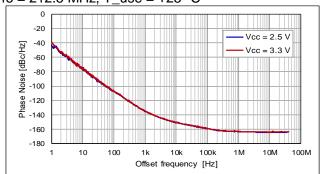
fo = 156.25 MHz, T_use = +25 °C



V_{CC}	Phase Jitter*
2.5 V	45 fs
3.3 V	46 fs

* Offset frequency: 12 kHz to 20 MHz

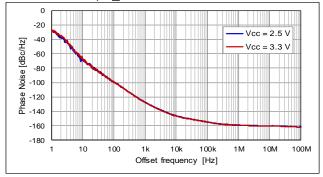
fo = 212.5 MHz, T use = $+25$ °C



V_{CC}	Phase Jitter*	
2.5 V	29 fs	
3.3 V	30 fs	

* Offset frequency: 12 kHz to 20 MHz

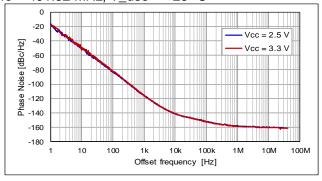
fo = 312.5 MHz, T_use = +25 °C



V_{CC}	Phase Jitter*
2.5 V	32 fs
3.3 V	31 fs

 * Offset frequency: 12 kHz to 20 MHz

fo = 491.52 MHz, T_use = +25 °C

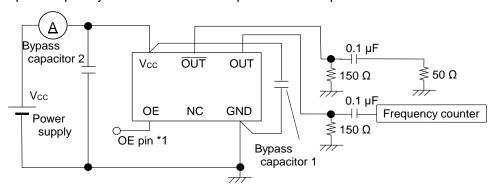


V_{CC}	Phase Jitter*
2.5 V	21 fs
3.3 V	21 fs

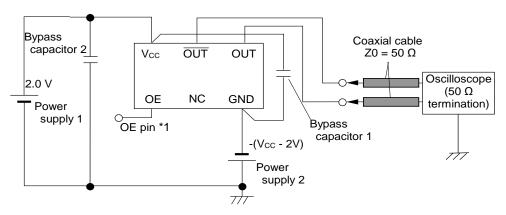
* Offset frequency: 12 kHz to 20 MHz

[8] Test Circuit

(8-1) Output Frequency and Current Consumption Test Setup



(8-2) Waveform Observation Test Setup



- * Each output trace should be same length
- * To measure Disable Current, OE terminal is connected to GND

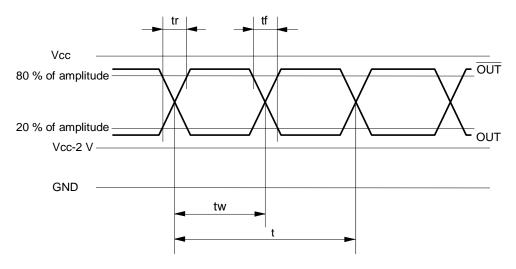
(8-3) Conditions

- (1) Oscilloscope
 - The bandwidth should be a minimum of 5 times wider than the measurement frequency
- (2) A 0.1 μF and a 10 μF bypass capacitor should be connected between V_{CC} and GND pins located close to the device
- (3) Use a current meter with a low internal impedance
- (4) Power Supply
 - Power supply startup time (0 % V_{CC} \rightarrow 90 % V_{CC}) should be more than 150 µs Power supply impedance should be as low as possible

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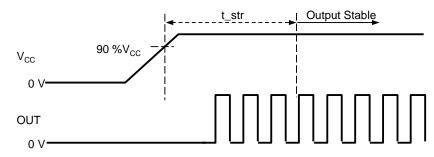
(8-4) Timing Chart

(1) Output Waveform and Level



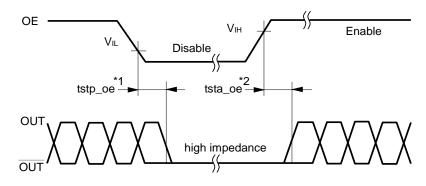
 $SYM = tw / t \times 100 [\%]$

(2) Output Frequency Timing



(3) OE Function and Timing

	9	
OE Terminal	Osc. Circuit	Output status
"H" or OPEN	Oscillation	Specified frequency is output: Enable
"L"	Oscillation	Output becomes high impedance: Disable



- *1 The period from $OE = V_{IL}$ to OUT = High impedance (Disable)
- *2 The period from $OE = V_{IH}$ to OUT = Enable
- * OE terminal voltage level should not exceed supply voltage when using OE function.

 Please note that OE rise time should not exceed supply voltage rise time at the start-up.

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Units: mm

[9] Outline Drawing and Recommended Footprint (9-1) SG3225EEN

3.2±0.2 #5 #2 #3 #2 #3 #2 #3 #2 #3 #2 #3 #3 #2 #3 #3 #3 #3 #4

CO.20

#3

CO.20

#6

O.5

O.5

Terminal coating: Au plating

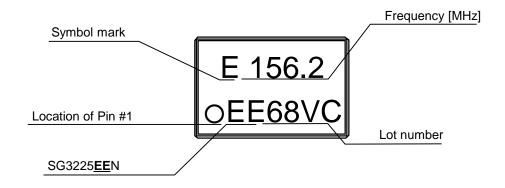
For stable operation, it is recommended that 0.1 μ F and 10 μ F bypass capacitors should be connected between V_{CC} and GND and placed as close to the V_{CC} pin as possible.

Reference Weight Typ.: 26 mg

Terminal Assignment

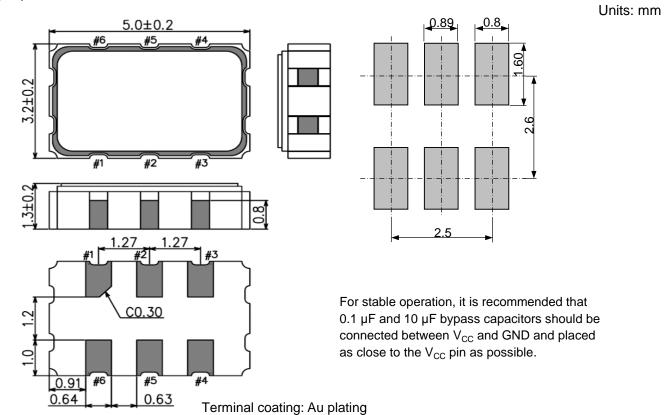
erminal Assignment				
Pin #	Connection	Function		
		OE terminal / active high		
#1	OE	OE function	Osc. circuit	Output
#1	00	"H" or OPEN	Oscillation	Specified frequency: Enable
		"L"	Oscillation	High impedance: Disable
#2	NC	_		
#3	GND	GND terminal		
#4	OUT	Output terminal (Positive)		
#5	ŌŪŦ	Output terminal (Negative)		
#6	V _{cc}	V _{CC} terminal		

Marking



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(9-2) SG5032EEN

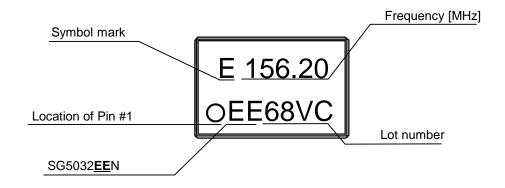


Reference Weight Typ.: 65 mg

Terminal Assignment

Pin #	Connection	Function			
		OE terminal / active high			
#1	OE	OE function	Osc. circuit	Output	
#1		"H" or OPEN	Oscillation	Specified frequency: Enable	
		"L" Oscillation High impedance: Disable			
#2	NC	_			
#3	GND	GND terminal			
#4	OUT	Output terminal (Positive)			
#5	ŌŪŦ	Output terminal (Negative)			
#6	V _{CC}	V _{CC} terminal			

Marking



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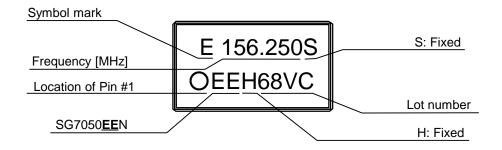
(9-3) SG7050EEN Units: mm 7.0 ± 0.2 1.80 #6 2.00 5.0±0.2 4.20 #2[°] #3 2.54 5.08 2.54 2.54 #21 /co.5 For stable operation, it is recommended that 2.6 $0.1~\mu F$ and $10~\mu F$ bypass capacitors should be connected between V_{CC} and GND and placed $\,$ as close to the $V_{\text{\footnotesize CC}}$ pin as possible. #6 #5 #4 1.4 Terminal coating: Au plating 0.26

Reference Weight Typ.: 165 mg

Terminal Assignment

enninai Assigninent				
Pin #	Connection	Function		
		OE terminal / active high		
#1	OE	OE function	Osc. circuit	Output
#1	OE	"H" or OPEN	Oscillation	Specified frequency: Enable
		"L"	Oscillation	High impedance: Disable
#2	NC	-		
#3	GND	GND terminal		
#4	OUT	Output terminal (Positive)		
#5	ŌŪŦ	Output terminal (Negative)		
#6	V _{CC}	V _{CC} terminal		

Marking



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[10] Moisture Sensitivity Level and Electro-Static Discharge Ratings

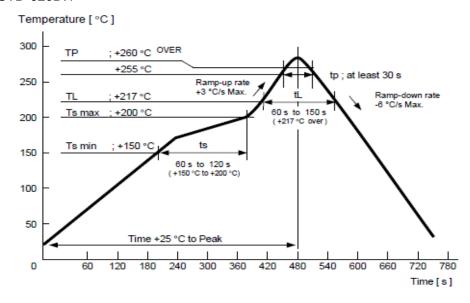
(10-1) Moisture Sensitivity Level (MSL)

Parameter	Specification	Conditions	
MSL	LEVEL 1	IPC/JEDEC J-STD-020D.1	

(10-2) Electro-Static Discharge (ESD)

Parameter	Specification	Conditions
HBM	2 000 V Min.	IEC 60749-26 Ed. 2.0:2006 (b), 100 pF, 1.5 kΩ, 3 times
MM	200 V Min.	IEC 60749-27 Ed. 2.0:2006 (b), 200 pF, 0 Ω, 1 time

[11] Reflow Profile IPC/JEDEC J-STD-020D.1



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Units: mm

[12] Packing Information

(12-1) SG3225EEN

(1) Packing Quantity

The last two digits of the Product Number (X1G005221xxxx \underline{xx} / X1G005511xxxx \underline{xx}) are a code that defines the packing quantity. The standard is "00" for a 2 000 pcs/Reel.

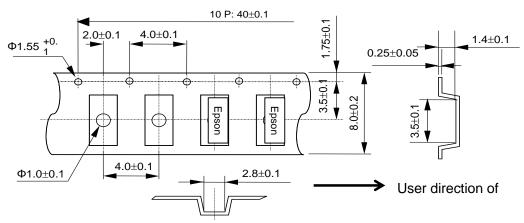
(2) Taping Specification

Subject to EIA-481, IEC-60286 and JIS C0806

1) Tape Dimensions

Carrier Tape Material: PS (Polystyrene)

Top Tape Material: PET (Polyethylene Terephthalate) + PE (Polyethylene)



2) Reel Dimensions

Center Material: PS (Polystyrene)

Reel Material: PS (Polystyrene)

Units: mm

3) Storage Environment

We recommend to keep at normal temperature and normal humidity in a packed condition.

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(12-2) SG5032EEN

(1) Packing Quantity

The last two digits of the Product Number (X1G005531xxxxxxx) are a code that defines the packing quantity. The standard is "00" for a 1 000 pcs/Reel.

0

User direction of feed

Top tape

(2) Taping Specification

Subject to EIA-481, IEC-60286 and JIS C0806

1) Tape Dimensions

Carrier Tape Material: PS (Polystyrene)

Top Tape Material: PET (Polyethylene Terephthalate)

0

0

0

Carrier tape

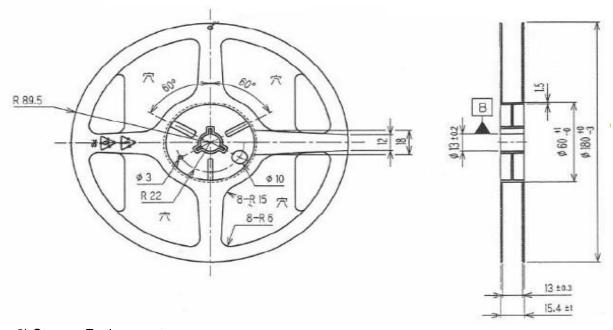
Symbol	Α	В	С	D	Е	F	G	Н
Dimension	Ф1.5	4.0	8.0	7.25	12.0	1.7	3.5	5.4

2) Reel Dimensions

Center Material: PS (Polystyrene) Reel Material: PS (Polystyrene)

Units: mm

Units: mm



3) Storage Environment

We recommend to keep at normal temperature and normal humidity in a packed condition.

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(12-3) SG7050EEN

(1) Packing Quantity

The last two digits of the Product Number (X1G005131xxxxxxx / X1G005551xxxxxxxx) are a code that defines the packing quantity. The standard is "00" for a 1 000 pcs/Reel.

(2) Taping Specification

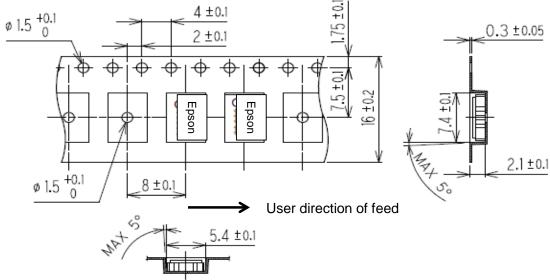
Subject to EIA-481, IEC-60286 and JIS C0806

1) Tape Dimensions

Carrier Tape Material: PS (Polystyrene)

Top Tape Material: PET (Polyethylene Terephthalate)

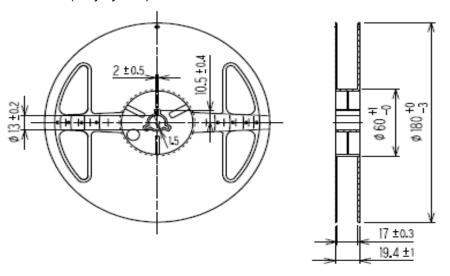
Units: mm



2) Reel Dimensions

Center Material: PS (Polystyrene) Reel Material: PS (Polystyrene)

Units: mm



3) Storage Environment

We recommend to keep at normal temperature and normal humidity in a packed condition.

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[13] Handling Precautions

Prior to using this product, please carefully read the section entitled "Precautions" on our Web site (https://www5.epsondevice.com/en/information/#precaution) for instructions on how to handle and use the product properly to ensure optimal performance of the product in your equipment.

Before using the product under any conditions other than those specified therein,

please consult with us to verify and confirm that the performance of the product will not be negatively affected by use under such conditions.

In addition to the foregoing precautions, in order to avoid the deteriorating performance of the product, we strongly recommend that you DO NOT use the product under ANY of the following conditions:

- (1) Do not expose this product to excessive mechanical shock or vibration.
- (2) This product can be damaged by mechanical shock during the soldering process depending on the equipment used, process conditions, and any impact forces experienced. Always follow appropriate procedures, particularly when changing the assembly process in any way and be sure to follow applicable process qualification standards before starting production.
- (3) These devices are sensitive to ESD, use appropriate precautions during handling, assembly, test, shipment, and installation.
- (4) The use of ultrasonic technology for cleaning, bonding, etc. can damage the Xtal unit inside this product.

 Please carefully check for this consideration before using ultrasonic equipment for volume production with this product.
- (5) Noise and ripple on the power supply may have undesirable affects on operation and cause degradation of phase noise characteristics. Evaluate the operation of this device with appropriate power supplies carefully before use.
- (6) When applying power, ensure that the supply voltage increases monotonically for proper operation. On power down, do not reapply power until the supplies, bypass capacitors, and any bulk capacitors are completely discharged since that may cause the unit to malfunction.
- (7) Aging specifications are estimated from environmental reliability tests and expected frequency variation over time. They do not provide a guarantee of aging over the product lifecycle.
- (8) The metal cap on top of the device is directly connected to the GND terminal. Take necessary precautions to prevent any conductor not at ground potential from contacting the cap as that could cause a short circuit to GND.
- (9) Do not route any signal lines, supply voltage lines, or GND lines underneath the area where the oscillators are mounted including any internal layers and on the opposite side of the PCB. To avoid any issues due to interference of other signal lines, please take care not to place signal lines near the product as this may have an adverse affect on the performance of the product.
- (10) A bypass capacitor of the recommended value(s) must be connected between the V_{CC} and GND terminals of the product. Whenever possible, mount the capacitor(s) on the same side of the PCB and as close to the product as possible to keep the routing traces short.
- (11) Power supply connections to V_{CC} and GND pins should be routed as thick as possible while keeping the high frequency impedance low in order to get the best performance.
- (12) The use of a filter or similar element in series with the power supply connections to protect from electromagnetic radiation noise may increase the high frequency impedance of the power supply line and may cause the oscillator to not operate properly. Please verify the design to ensure sufficient operational margin prior to use.
- (13) Keep PCB routing from the output terminal(s) to the load as short as possible for best performance.
- (14) The Enable (OE) input terminal is high impedance and so susceptible to noise. Connect it to a low impedance source when used and when not used it is recommended to connect it to Vcc for active high inputs and GND for active low inputs.
- (15) Do not short the output to GND as that will damage the product. Always use with an appropriate load resistor connected.
- (16) This product should be reflowed no more than 3 times.

 If rework is needed after reflow, please correct it with a soldering iron with the tip set for a temperature of +350 °C or less and only contact each terminal once and for no more than 5 seconds.

 If this product is mounted on the bottom of the board during a reflow please check that it soldered down properly afterwards.

valiability of mounting conditions]				
Reflow on the board	Avallable			
Reflow under the board	The parts may fall. Please judge whether it is possible to implement.			
Soldering pot/bath (Dip soldering system, Flow soldering system)	Not Avallable			
Soldering iron	Avallable			

- (17) Product failures during the warranty period only apply when the product is used according to the recommended operating conditions described in the specifications. Products that have been opened for analysis or damaged will not be covered. It is recommended to store and use in normal temperature and humidity environments described in the specifications to ensure frequency accuracy and prevent moisture condensation. If the product is stored for more than one year, please confirm the pin solderability prior to use.
- (18) If the oscillation circuit is exposed to condensation, the frequency may change or oscillation may stop. Do not use in any conditions where condensation occurs.
- (19) Do not store or use the product in an environment where it can be exposed to chemical substances that are corrosive to metal or plastics such as salt water, organic solvents, chemical gasses, etc. Do not use the product when it is exposed to sunlight, dust, corrosive gasses, or other materials for long periods of time.
- (20) When using water-soluble solder flux make sure to completely remove the flux residue after soldering.

 Pay particular attention when the residues contain active halogens which will negatively affect the product and its performance.
- (21) Terminals on the side of the product are internally connected to the IC, be careful not to cause short-circuits or reduce the insulation resistance of them in any way.
- (22) Should any customer use the product in any manner contrary to the precautions and/or advice herein, such use shall be done at the customer's own risk.

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PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Seiko Epson, all environmental initiatives operate under the Plan-Do-Check-Action (PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification. ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation

WORKING FOR HIGH QUALITY

In order provide high quality and reliable products and services than meet customer needs, Seiko Epson made early efforts towards obtaining ISO9000 series certification and has acquired ISO9001 for all business establishments in Japan and abroad. We have also acquired IATF 16949 certification that is requested strongly by major manufacturers as standard.

IATF 16949 is the international standard that added the sectorspecific supplemental requirements for automotive industry based on ISO9001.

Explanation of marks used in this datasheet



*About the products without the Pb-free mark.

Contains Pb in products exempted by EU RoHS directive

(Contains Pb in sealing glass, high melting temperature type solder or other)

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